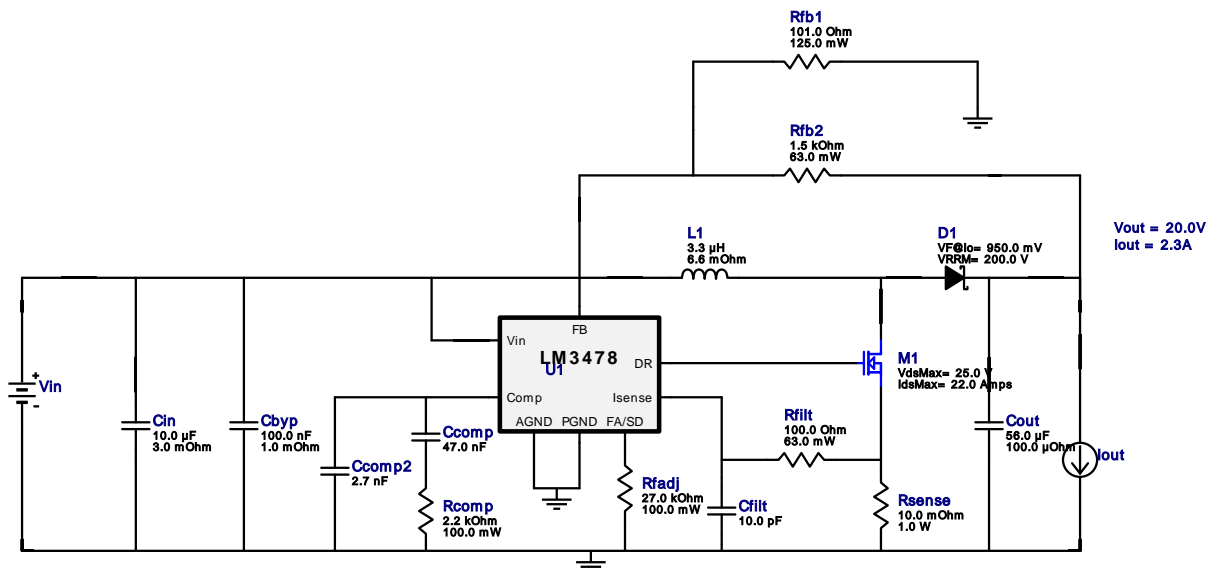









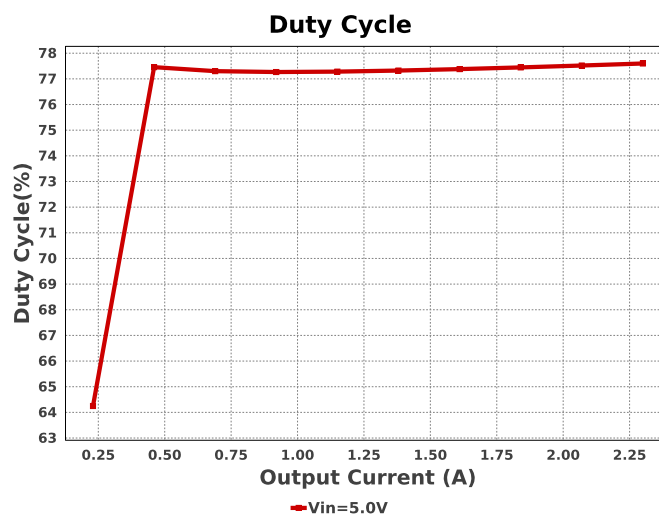
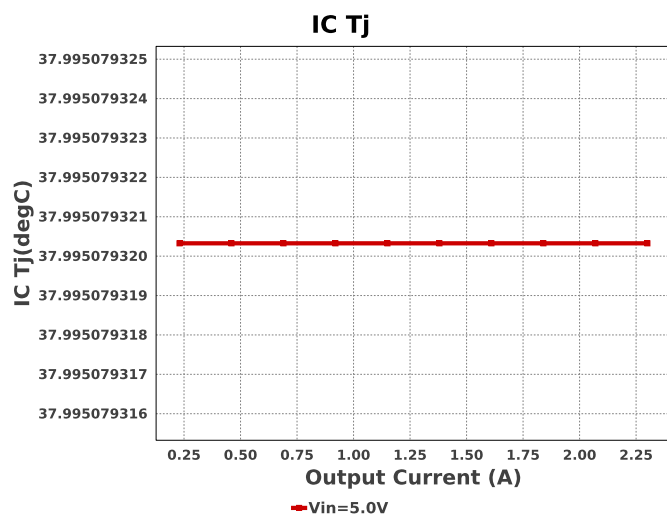
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Topology = Boost  
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BOM Cost = NA  
BOM Count = 16  
Total Pd = 5.53W

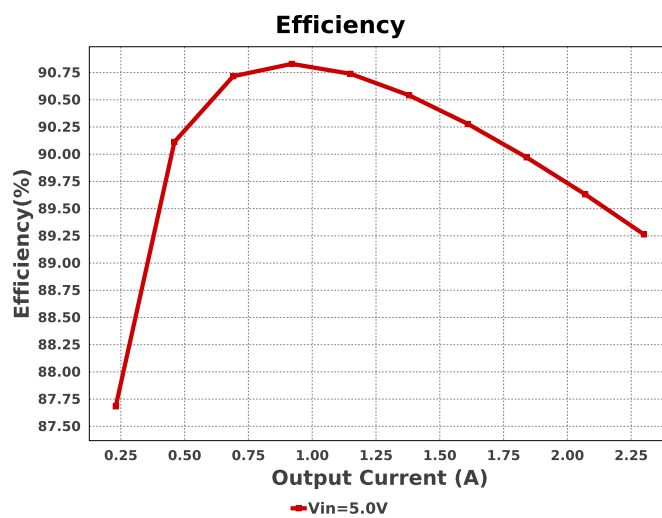
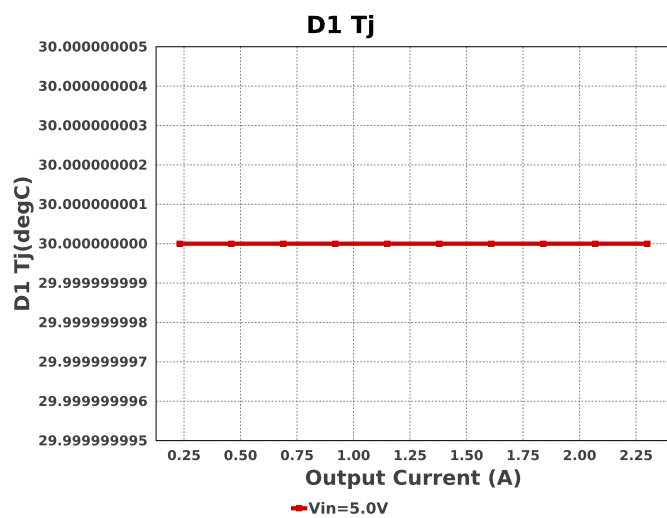
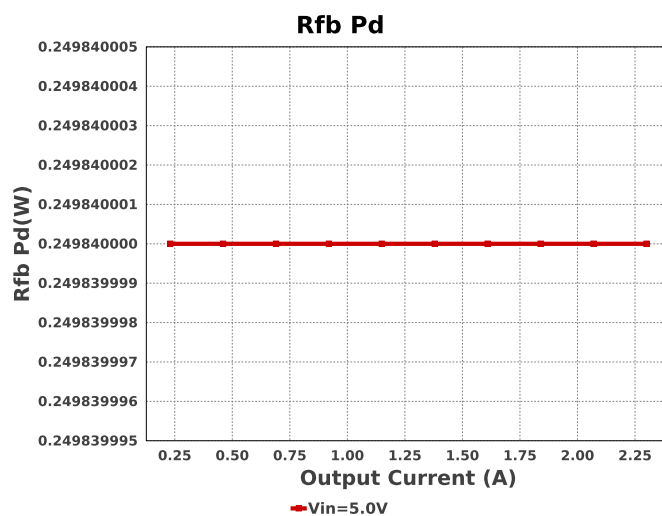
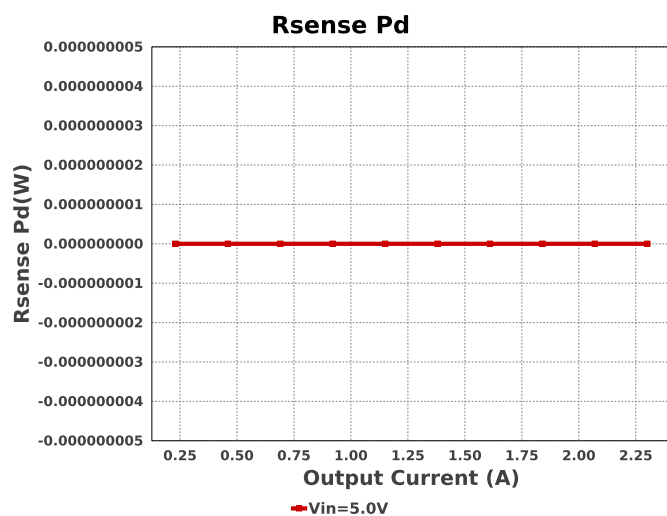
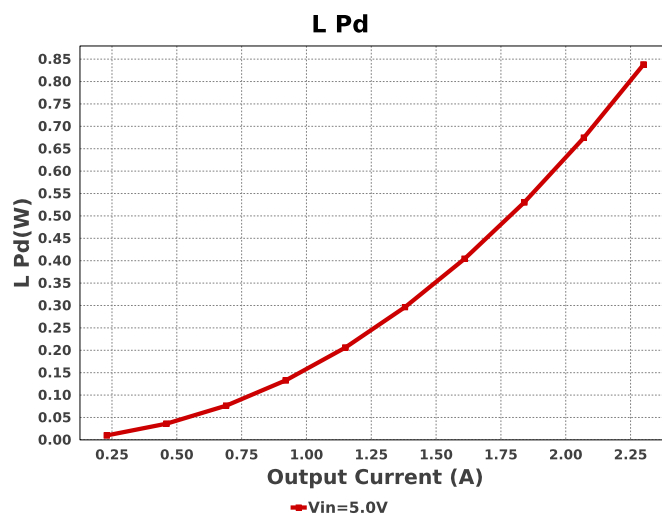
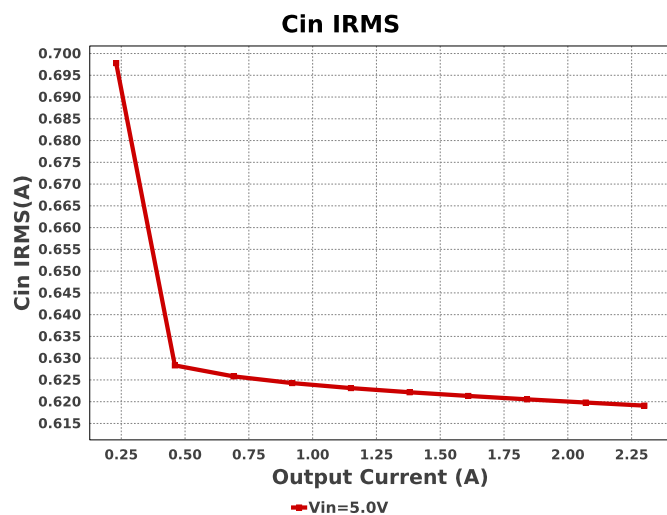
Design : 2 LM3478MM/NOPB  
LM3478MM/NOPB 5V-5V to 20.00V @ 2.3A

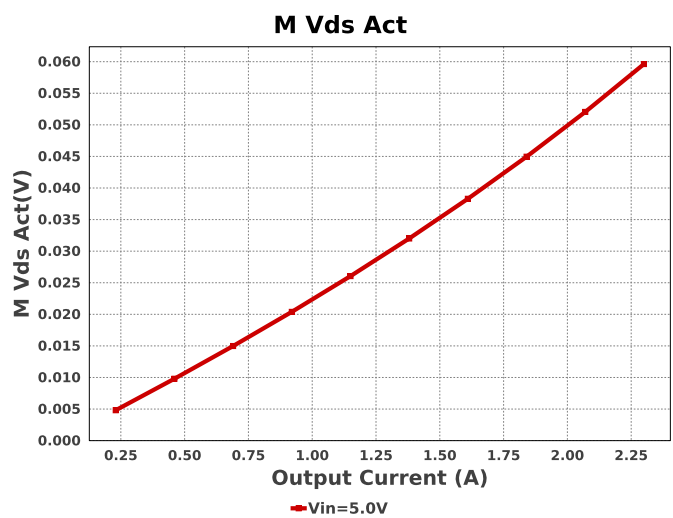
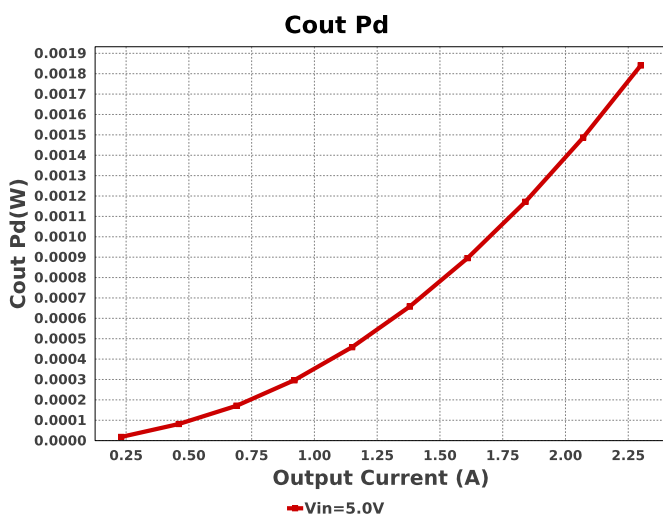
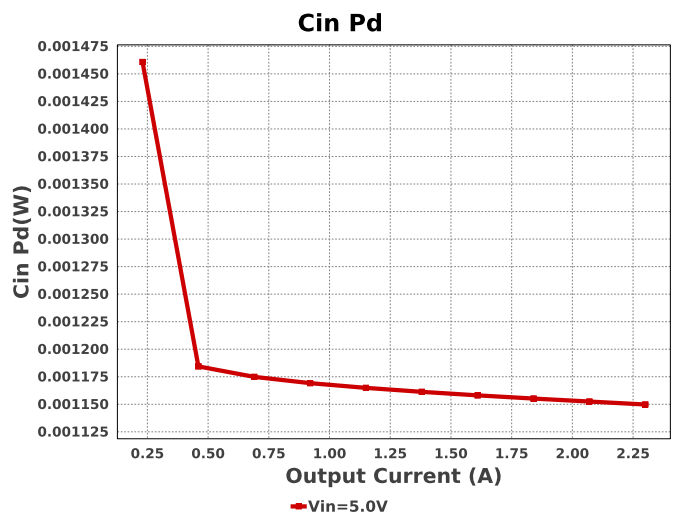
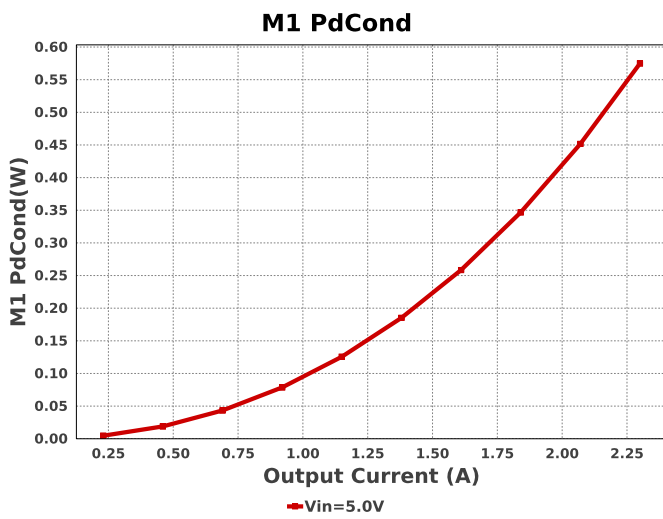
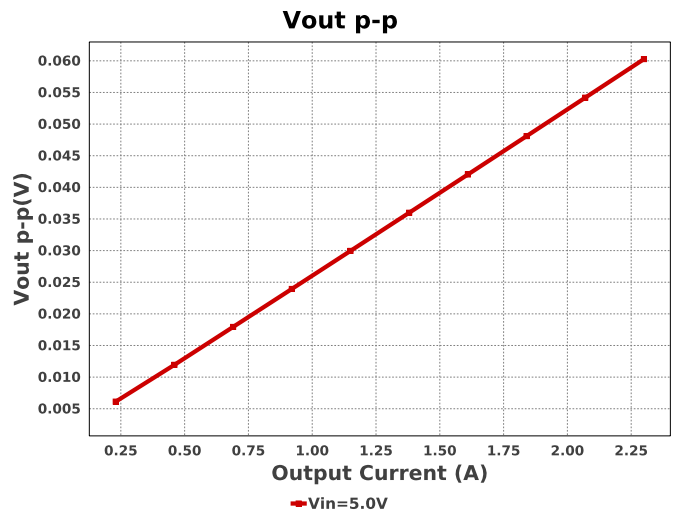
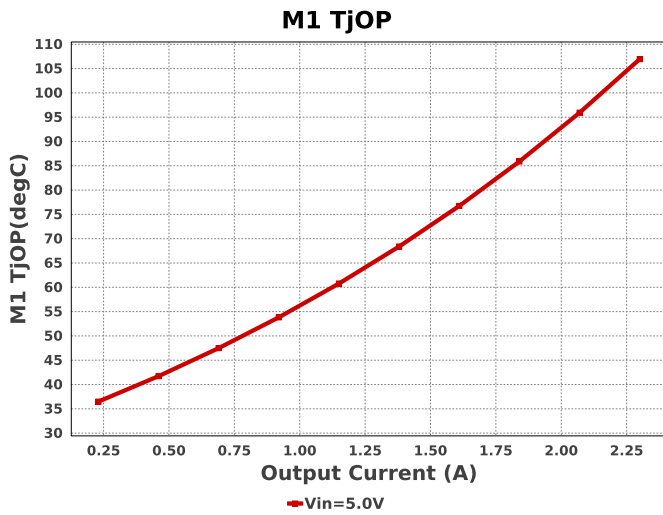


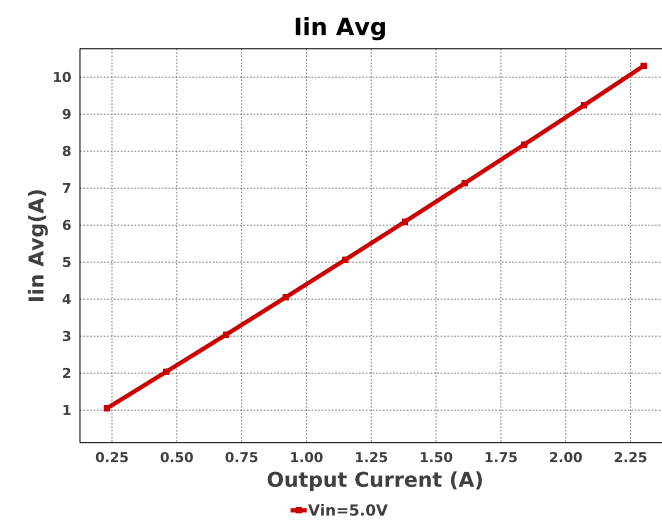
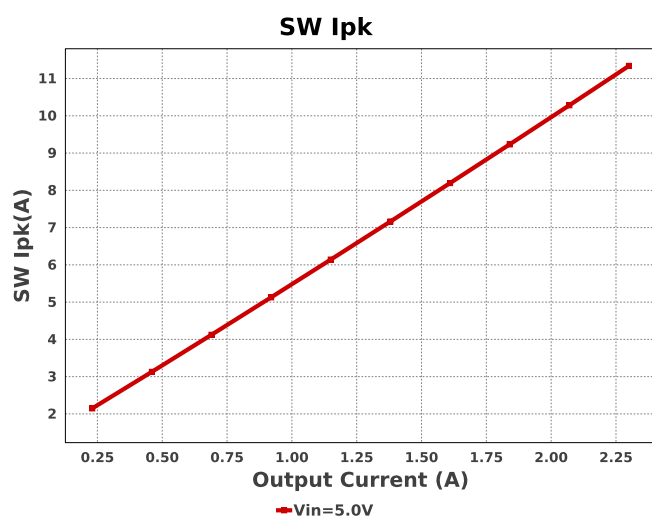
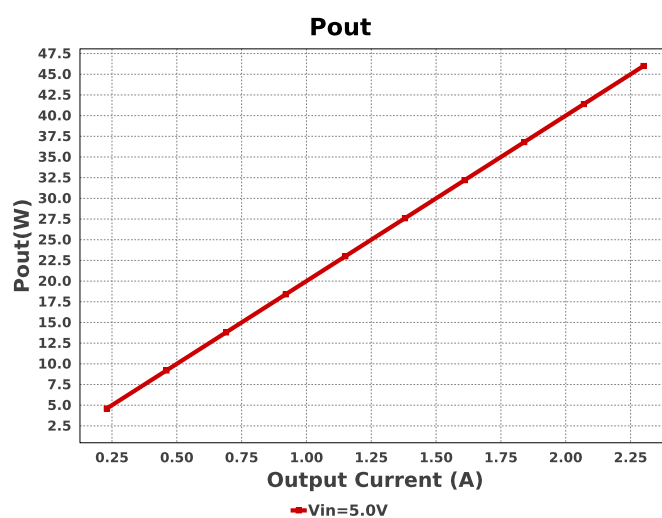
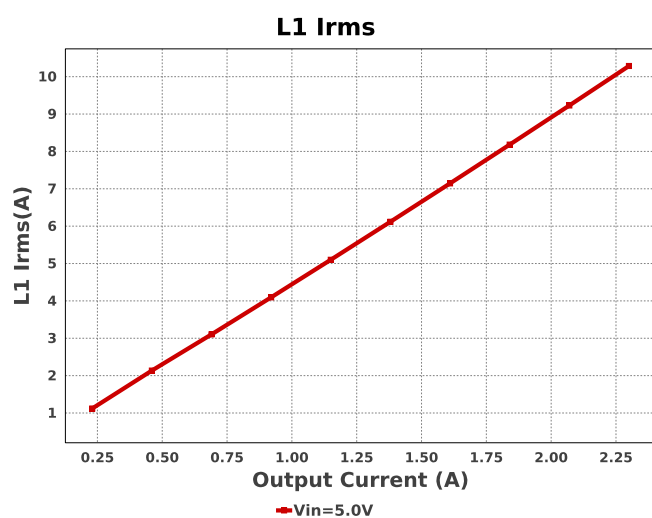
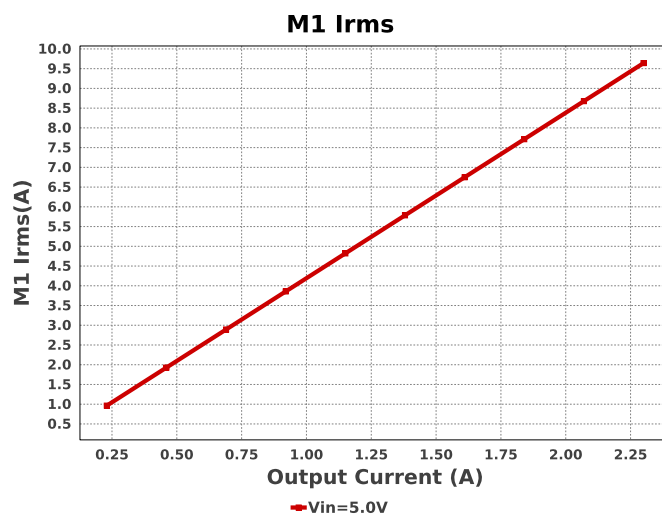
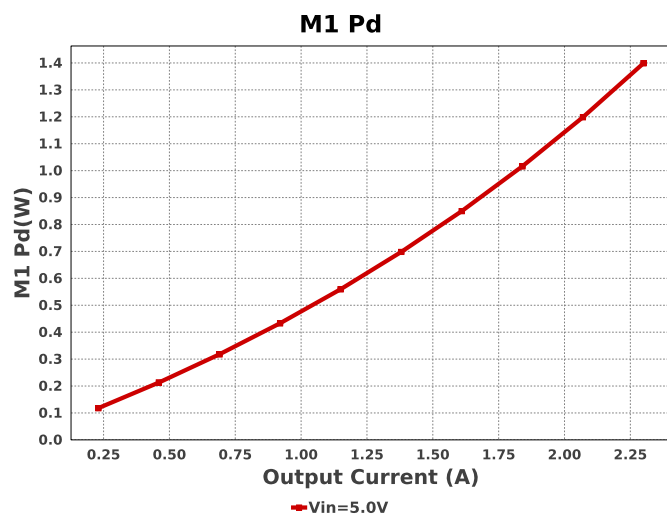
Name	Manufacturer	Part Number	Properties	Qty	Price	Footprint
Cbyp	MuRata	GRM155R70J104KA01D Series= X7R	Cap= 100.0 nF ESR= 1.0 mOhm VDC= 6.3 V IRMS= 0.0 A	1	\$0.01	 0402 3 mm <sup>2</sup>
Ccomp	Kemet	C0805C473J3GACTU Series= C0G/NP0	Cap= 47.0 nF VDC= 25.0 V IRMS= 0.0 A	1	\$0.23	 0805 7 mm <sup>2</sup>
Ccomp2	TDK	C2012C0G1H272J060AA Series= C0G/NP0	Cap= 2.7 nF VDC= 50.0 V IRMS= 0.0 A	1	\$0.03	 0805 7 mm <sup>2</sup>
Cfilt	Samsung Electro-Mechanics	CL21C100JBANNNC Series= C0G/NP0	Cap= 10.0 pF VDC= 50.0 V IRMS= 0.0 A	1	\$0.01	 0805 7 mm <sup>2</sup>
Cin	Kemet	C0805C106K8PACTU Series= X5R	Cap= 10.0 uF ESR= 3.0 mOhm VDC= 10.0 V IRMS= 11.43 A	1	\$0.03	 0805 7 mm <sup>2</sup>
Cout	CUSTOM	CUSTOM Series= ?	Cap= 56.0 uF ESR= 100.0 uOhm VDC= 28.57 V IRMS= 4.119 A	1	NA	CUSTOM 0 mm <sup>2</sup>
D1	SMC Diode Solutions	SBRD10200TR	VF@Io= 950.0 mV VRRM= 200.0 V	1	\$0.12	 DPAK 102 mm <sup>2</sup>

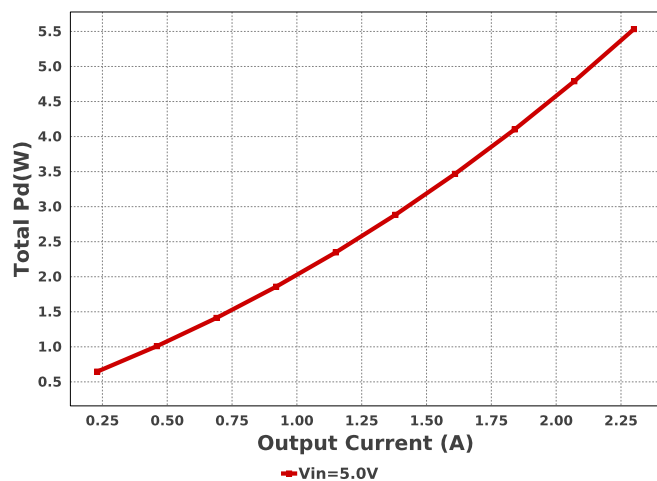
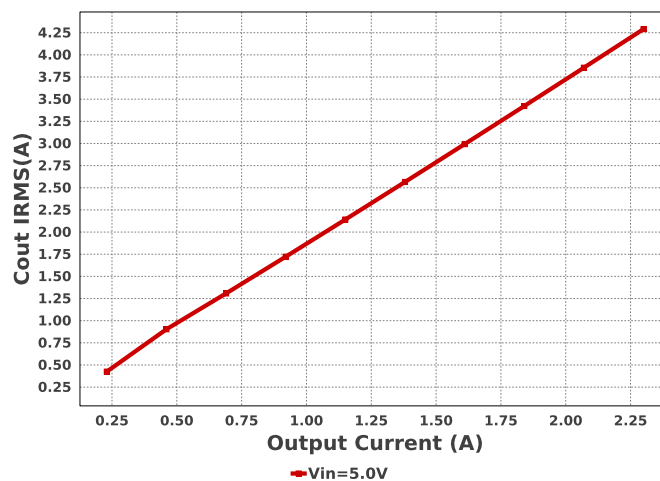
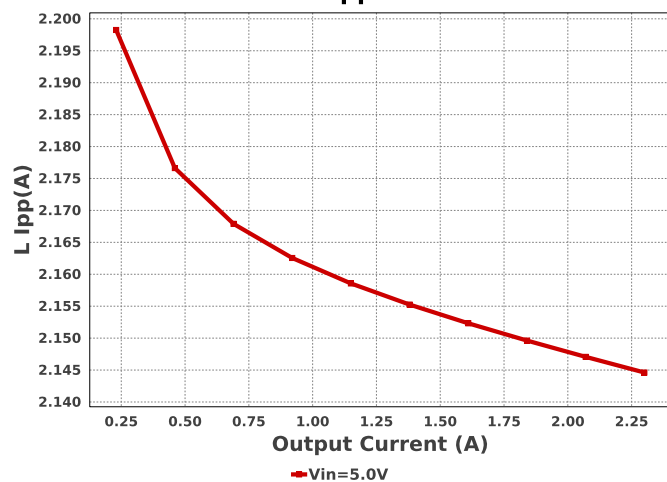
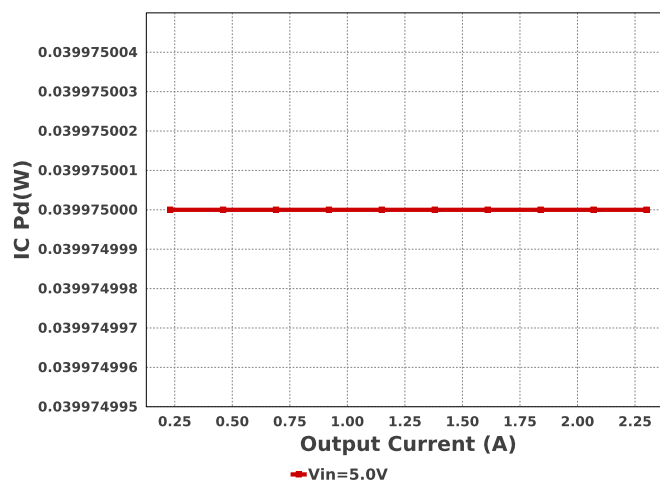
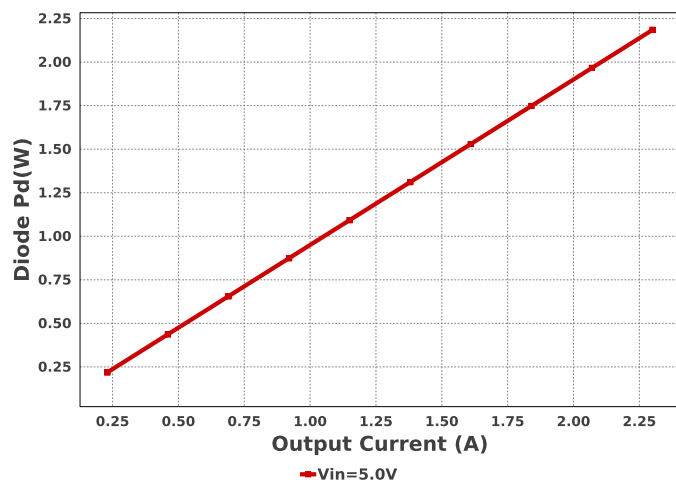
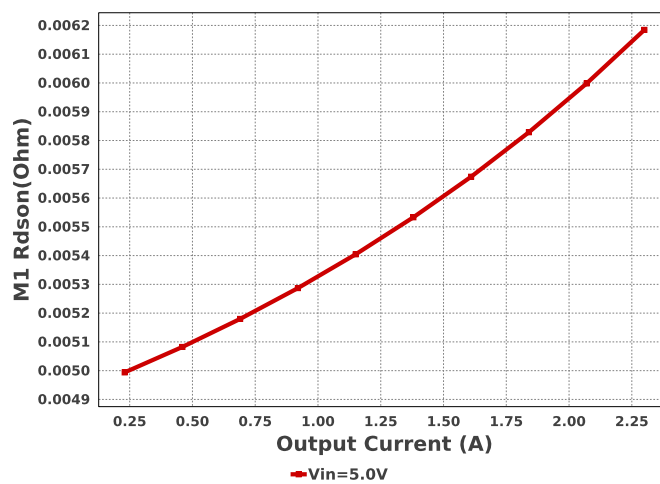
Name	Manufacturer	Part Number	Properties	Qty	Price	Footprint
L1	Bourns	SRP1270-3R3M	L= 3.3 $\mu$ H 6.6 mOhm	1	\$0.72	 SRP1270 246 mm <sup>2</sup>
M1	Texas Instruments	CSD16327Q3	VdsMax= 25.0 V IdsMax= 22.0 Amps	1	\$0.34	 DQG0008A 18 mm <sup>2</sup>
Rcomp	Yageo	RC0603FR-072K2L Series= ?	Res= 2.2 kOhm Power= 100.0 mW Tolerance= 1.0%	1	\$0.01	 0603 5 mm <sup>2</sup>
Rfadj	Yageo	RC0603FR-0727KL Series= ?	Res= 27.0 kOhm Power= 100.0 mW Tolerance= 1.0%	1	\$0.01	 0603 5 mm <sup>2</sup>
Rfb1	Yageo	RT0805BRD07101RL Series= RT0805	Res= 101.0 Ohm Power= 125.0 mW Tolerance= 0.1%	1	NA	 0805 7 mm <sup>2</sup>
Rfb2	Vishay-Dale	CRCW04021K50FKED Series= CRCW..e3	Res= 1.5 kOhm Power= 63.0 mW Tolerance= 1.0%	1	\$0.01	 0402 3 mm <sup>2</sup>
Rfilt	Vishay-Dale	CRCW0402100RFKED Series= CRCW..e3	Res= 100.0 Ohm Power= 63.0 mW Tolerance= 1.0%	1	\$0.01	 0402 3 mm <sup>2</sup>
Rsense	Vishay-Dale	WSLP1206R0100FEA Series= WSL	Res= 10.0 mOhm Power= 1.0 W Tolerance= 1.0%	1	\$0.18	 1206 11 mm <sup>2</sup>
U1	Texas Instruments	LM3478MM/NOPB	Switcher	1	\$0.88	 MUA08A 24 mm <sup>2</sup>

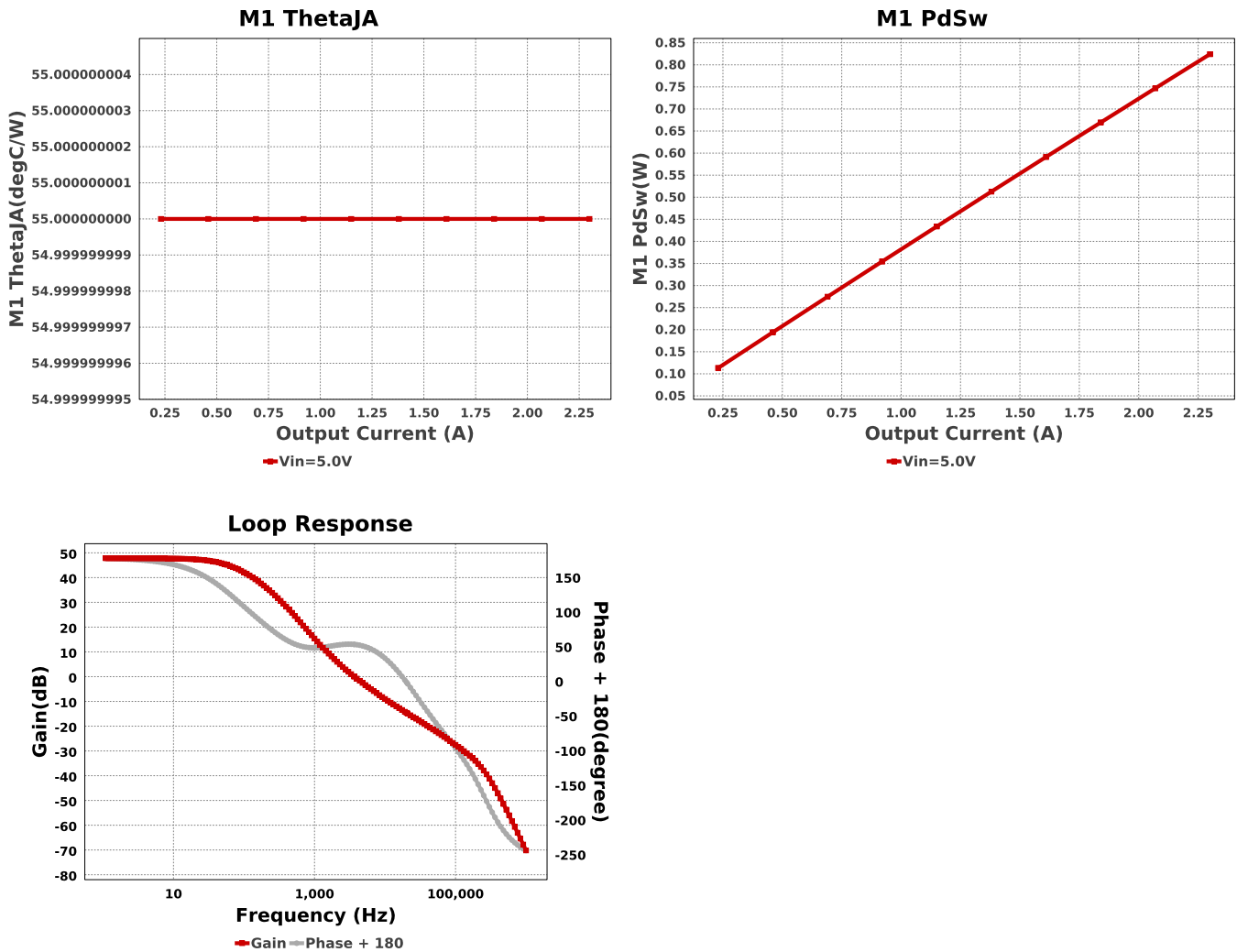








**Total Pd****Cout IRMS****L Ipp****IC Pd****Diode Pd****M1 Rdson**



## Operating Values

#	Name	Value	Category	Description
1.	BOM Count	16		Total Design BOM count
2.	Total BOM	NA		Total BOM Cost
3.	Cin IRMS	619.098 mA	Capacitor	Input capacitor RMS ripple current
4.	Cin Pd	1.15 mW	Capacitor	Input capacitor power dissipation
5.	Cout IRMS	4.291 A	Capacitor	Output capacitor RMS ripple current
6.	Cout Pd	1.841 mW	Capacitor	Output capacitor power dissipation
7.	D1 Tj	30.0 degC	Diode	D1 junction temperature
8.	Diode Pd	2.185 W	Diode	Diode power dissipation
9.	IC Pd	39.975 mW	IC	IC power dissipation
10.	IC Tj	37.995 degC	IC	IC junction temperature
11.	IC Tolerance	24.3 mV	IC	IC Feedback Tolerance
12.	ICThetaJA	200.0 degC/W	IC	IC junction-to-ambient thermal resistance
13.	Iin Avg	10.307 A	IC	Average input current
14.	L Ipp	2.145 A	Inductor	Peak-to-peak inductor ripple current
15.	L Pd	837.97 mW	Inductor	Inductor power dissipation
16.	L1 Irms	10.286 A	Inductor	Inductor ripple current
17.	M Vds Act	59.625 mV	Mosfet	M Vds
18.	M1 Irms	9.641 A	Mosfet	M1 MOSFET Irms
19.	M1 Pd	1.399 W	Mosfet	M1 MOSFET total power dissipation
20.	M1 PdCond	574.83 mW	Mosfet	M1 MOSFET conduction losses
21.	M1 PdSw	824.18 mW	Mosfet	M1 MOSFET switching losses
22.	M1 Rdson	6.185 mOhm	Mosfet	Drain-Source On-resistance
23.	M1 ThetaJA	55.0 degC/W	Mosfet	MOSFET junction-to-ambient thermal resistance
24.	M1 TjOP	106.946 degC	Mosfet	M1 MOSFET junction temperature
25.	Cin Pd	1.15 mW	Power	Input capacitor power dissipation
26.	Cout Pd	1.841 mW	Power	Output capacitor power dissipation
27.	Diode Pd	2.185 W	Power	Diode power dissipation
28.	IC Pd	39.975 mW	Power	IC power dissipation
29.	L Pd	837.97 mW	Power	Inductor power dissipation
30.	M1 Pd	1.399 W	Power	M1 MOSFET total power dissipation
31.	M1 PdCond	574.83 mW	Power	M1 MOSFET conduction losses
32.	M1 PdSw	824.18 mW	Power	M1 MOSFET switching losses

#	Name	Value	Category	Description
33.	Rfb Pd	249.84 mW	Power	Rfb Power Dissipation
34.	Rsense Pd	0.0 W	Power	LED Current Rsns Power Dissipation
35.	Total Pd	5.533 W	Power	Total Power Dissipation
36.	Rfb Pd	249.84 mW	Resistor	Rfb Power Dissipation
37.	Rsense Pd	0.0 W	Resistor	LED Current Rsns Power Dissipation
38.	Cross Freq	3.674 kHz	System	Bode plot crossover frequency
39.	Duty Cycle	77.599 %	Information	
			System	Duty cycle
40.	Efficiency	89.263 %	Information	
			System	Steady state efficiency
41.	FootPrint	553.0 mm <sup>2</sup>	Information	
			System	Total Foot Print Area of BOM components
42.	Frequency	536.973 kHz	Information	
			System	Switching frequency
43.	Gain Marg	-14.6 dB	Information	
			System	Bode Plot Gain Margin
44.	Iout	2.3 A	Information	
			System	Iout operating point
45.	Low Freq Gain	47.797 dB	Information	
			System	Gain at 1Hz
46.	Mode	CCM	Information	
			System	Conduction Mode
47.	Phase Marg	54.542 deg	Information	
			System	Bode Plot Phase Margin
48.	Pout	46.0 W	Information	
			System	Total output power
49.	SW Ipk	11.34 A	Information	
			System	Peak switch current
50.	Vin	5.0 V	Information	
			System	Vin operating point
51.	Vout	20.0 V	Information	
			System	Operational Output Voltage
52.	Vout Actual	19.973 V	Information	
			System	Vout Actual calculated based on selected voltage divider resistors
53.	Vout Tolerance	2.98 %	Information	
			System	Vout Tolerance based on IC Tolerance (no load) and voltage divider resistors if applicable
54.	Vout p-p	60.273 mV	Information	
			System	Peak-to-peak output ripple voltage

## Design Inputs

Name	Value	Description
Iout	2.3	Maximum Output Current
VinMax	5.0	Maximum input voltage
VinMin	5.0	Minimum input voltage
Vout	20.0	Output Voltage
base_pn	LM3478	Base Product Number
source	DC	Input Source Type
Ta	30.0	Ambient temperature



## WEBENCH® Assembly

### Component Testing

Some published data on components in datasheets such as Capacitor ESR and Inductor DC resistance is based on conservative values that will guarantee that the components always exceed the specification. For design purposes it is usually better to work with typical values. Since this data is not always available it is a good practice to measure the Capacitance and ESR values of  $C_{in}$  and  $C_{out}$ , and the inductance and DC resistance of  $L1$  before assembly of the board. Any large discrepancies in values should be electrically simulated in WEBENCH to check for instabilities and thermally simulated in WebTHERM to make sure critical temperatures are not exceeded.

### Soldering Component to Board

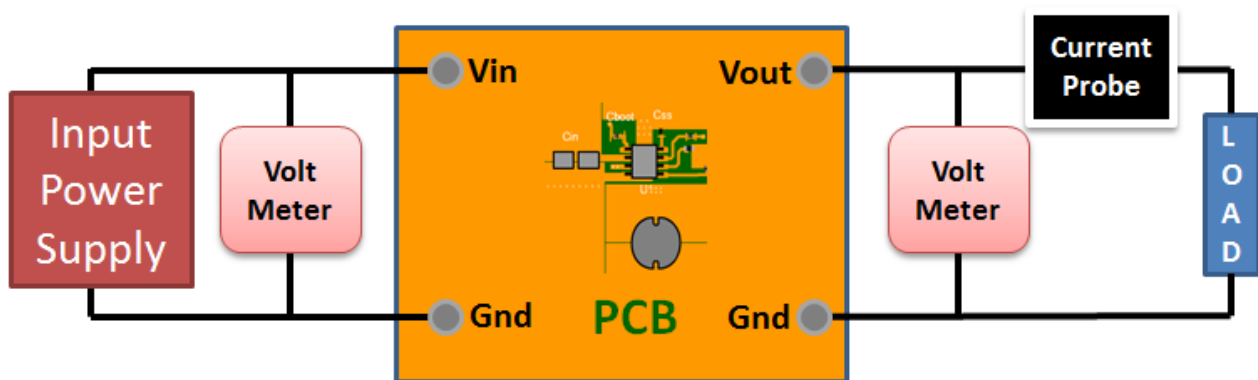
If board assembly is done in house it is best to tack down one terminal of a component on the board then solder the other terminal. For surface mount parts with large tabs, such as the DPAK, the tab on the back of the package should be pre-tinned with solder, then tacked into place by one of the pins. To solder the tab town to the board place the iron down on the board while resting against the tab, heating both surfaces simultaneously. Apply light pressure to the top of the plastic case until the solder flows around the part and the part is flush with the PCB. If the solder is not flowing around the board you may need a higher wattage iron (generally 25W to 30W is enough).

### Initial Startup of Circuit

It is best to initially power up the board by setting the input supply voltage to the lowest operating input voltage 5.0V and set the input supply's current limit to zero. With the input supply off connect up the input supply to  $V_{in}$  and GND. Connect a digital volt meter and a load if needed to set the minimum lout of the design from  $V_{out}$  and GND. Turn on the input supply and slowly turn up the current limit on the input supply. If the voltage starts to rise on the input supply continue increasing the input supply current limit while watching the output voltage. If the current increases on the input supply, but the voltage remains near zero, then there may be a short or a component misplaced on the board. Power down the board and visually inspect for solder bridges and recheck the diode and capacitor polarities. Once the power supply circuit is operational then more extensive testing may include full load testing, transient load and line tests to compare with simulation results.

### Load Testing

The setup is the same as the initial startup, except that an additional digital voltmeter is connected between  $V_{in}$  and GND, a load is connected between  $V_{out}$  and GND and a current meter is connected in series between  $V_{out}$  and the load. The load must be able to handle at least rated output power + 50% ( 7.5 watts for this design). Ideally the load is supplied in the form of a variable load test unit. It can also be done in the form of suitably large power resistors. When using an oscilloscope to measure waveforms on the prototype board, the ground leads of the oscilloscope probes should be as short as possible and the area of the loop formed by the ground lead should be kept to a minimum. This will help reduce ground lead inductance and eliminate EMI noise that is not actually present in the circuit.

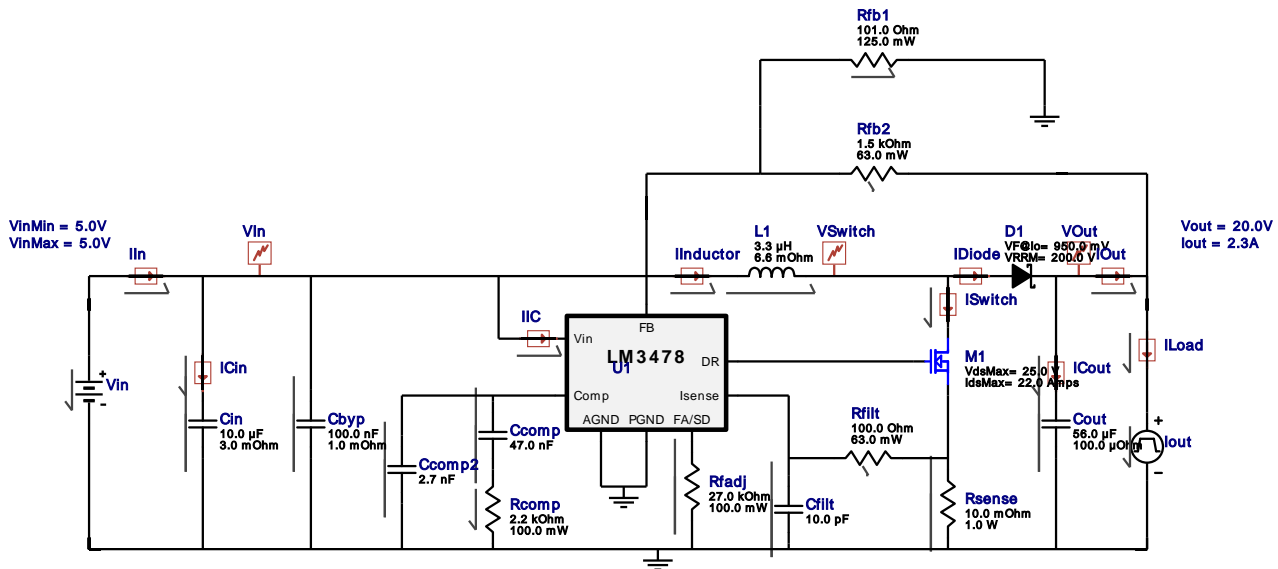


# WEBENCH® Electrical Simulation Report

Design Id = 2

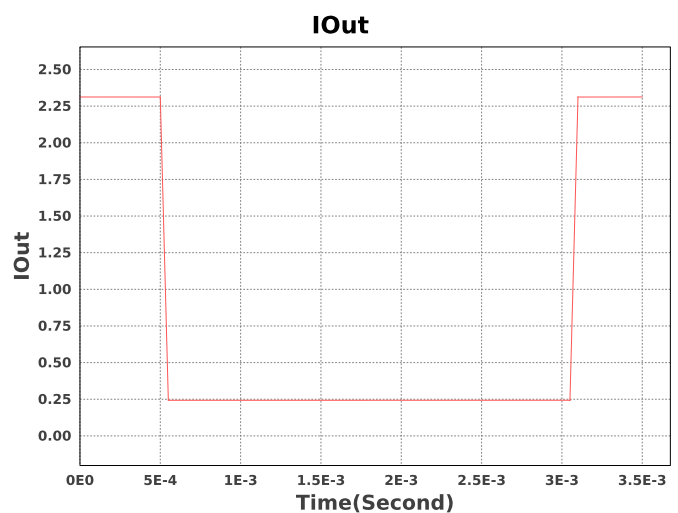
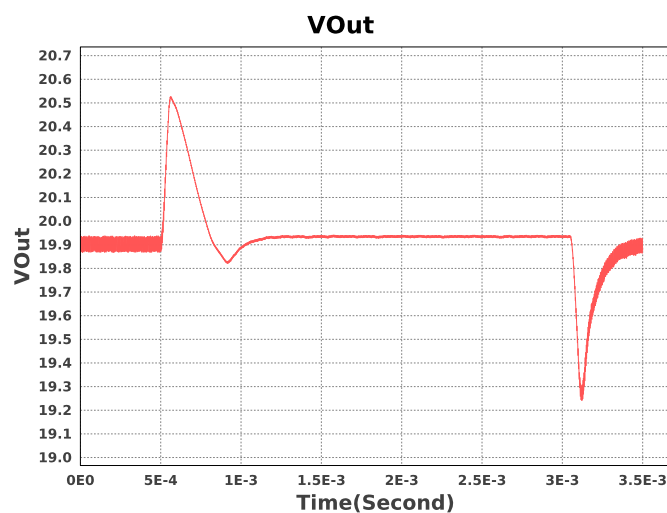
sim\_id = 13

Simulation Type = Load Transient



## Simulation Parameters

#	Name	Parameter Name	Description	Values
1.	Iout	signal_type	Signal Type	PULSE
		I1	Initial Current	2.3 A
		I2	Peak Current	0.22999999999999998 A
		Td	Initial Delay Time	0.5m Sec
		Tr	Rise Time	50u Sec
		Tf	Fall Time	50u Sec
		Pw	Pulse Width	2.5m Sec



## Design Assistance

1. Master key : F1D7F473A21C75E1[v1]

2. **LM3478** Product Folder : <http://www.ti.com/product/LM3478> : contains the data sheet and other resources.

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